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a U.S. GOVERNMENT PRINTING OFFICE: 1987 — 748-129/60911

1. SCOPE			
1.1 Scope. This drawing dewith 1.2.1 of MIL-STD-883, "Pronon-JAN devices".	scribes device requinovisions for the use	rements for class B m of MIL-STD-883 in co	icrocircuits in accordance njunction with compliant
1.2 Part number. The comple	ete part number shall	l be as shown in the	following example:
<u>5962-88652</u>		<u>E</u> 	X
Drawing number	Device type (1.2.1)	Case outline (1.2.2)	Lead finish per MIL-M-38510
1.2.1 <u>Device types</u> . The de	vice types shall iden	ntify the circuit fun	ction as follows:
Device type	Generic number	<u>C1</u> 1	rcuit function
01 02	54FCT182 54FCT182A		carry lookahead generator carry lookahead generator
1.2.2 <u>Case outlines</u> . The cas follows:	ase outlines shall be	e as designated in ap	pendix C of MIL-M-38510, and
Outline letter	<u>Ca</u> s	se outline	
E F 2	D-2 (16-lead, .840' F-5 (16-lead, .440' C-2 (20-terminal,	" x .310" x .200"), di " x .285" x .085"), f .358" x .358" x .100"	ual-in-line package lat package), square chip carrier package
1.3 Absolute maximum rating	<u>s</u> . <u>1</u> /		
Supply voltage range Input voltage range Output voltage range Output diode current () DC output diode current DC output current Maximum power dissipation Thermal resistance, junct Storage temperature range Junction temperature (Solder	I _{IK})		to +6.0 V dc to V _{CC} + 0.5 V dc to V _{CC} + 0.5 V dc 38510, appendix C
1.4 Recommended operating co	onditions.		
Supply voltage range (V _C Maximum low level input Minimum high level input Case operating temperatu	voltage (V _{IH})	0.8 V dc	to +5.5 V dc 125°C
1/ All voltages referenced to $2/$ Must withstand the added P _I		it test; e.g., I _{OS} .	

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2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
 - 3. REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth table. The truth table shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
 - 3.2.4 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full case operating temperature range.
- $3.4\,$ Marking. Marking shall be in accordance with MIL-STD-883 (see $3.1\,$ herein). The part shall be marked with the part number listed in $1.2\,$ herein. In addition, the manufacturer's part number may also be marked as listed in $6.4\,$ herein
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.

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	TABLI	E I. Electrical p	performance charact	teristics.			- т	
Test	Symbo1	Condi	itions		Device	Lim	ii ts	Unit
	1	-55°C < To Y _{CC} = 5.0 unless other	<pre> < +125°C 'V dc ±10% wise specified</pre>	subgroup s 	type	Min	Max	<u> </u>
High level output voltage	v _{OH}	$ V_{T1} = 0.8 V$.	I _{OH} = -300 μA	1, 2, 3	All	4.3	İ	٧
-	 	VIH = 2.0 V	I _{OH} = -12 mA	1, 2, 3	A11	2.4		V
Low level output voltage	V _{OL}	VCC = 4.5 V, VIL = 0.8 V, VIH = 2.0 V	I _{OL.} = 300 μA	1, 2, 3	A11		0.2	٧
-	 	V _{IH} = 2.0 V	I _{OL} = 32 mA	1, 2, 3	All	l	0.5	V
Input clamp voltage	v _{IK}	V _{CC} = 4.5 V, I _{IN}	≖ -18 mA	1, 2, 3	A11		-1.2	Y
High level input current	IIH	V _{CC} = 5.5 V, V _{IN}	= 5.5 V	1, 2, 3	All		5.0	 μΑ
Low level input current	IIL	V _{CC} = 5.5 V, V _{IN}	= GND	1, 2, 3	A11		-5.0	μА
Short circuit output current	I _{0S}	$V_{CC} = 5.5 \text{ V} \frac{1}{},$	V _{OUT} = 0.0 V	1, 2, 3	All	-60		i mA
Quiescent power supply current (CMOS inputs)	Iccq	$\begin{vmatrix} V_{\text{IN}} \leq 0.2 & V & \text{or } V \\ V_{\text{CC}} = 5.5 & V, & f_{\text{I}} \end{vmatrix}$	IN > 5.3 V, = 0.0 MHz	1, 2, 3	All		1.5	mA
Power supply current (TTL inputs high)	ΔI CC	V _{CC} = 5.5 V, V _{IN}	= 3.4 V <u>2</u> /	1, 2, 3	A11		2.0	mA
Dynamic power supply current	ICCD	VCC = 5.5 V VIN > 5.3 V or V loutputs open, lone bit toggling	IN ≤ 0.2 V, : 50% duty cycle	<u>3/</u>	A11		0.3	mA/ MHz

See footnotes at end of table.

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	TABLE I.	Electrical p	erformanc	e character	istics - Con	tinued.			
Test	Symbo1	-55°(V _{CC} : unless (Condition C < T _C < † = 5.0 V do otherwise	s 125°C ±10% specified	Group A subgroups		Li Min	mits Max	Unit
Total power supply current 4/	LICC	VIN > 5.3 V VCC = 5.5 V Outputs open one bit togg	η,		1, 2, 3	 A11 		4.5	mA
	 	VIN = 3.4 V VCC = 5.5 V, Outputs open	, f _I = 10	MHZ,	e			5.5	mA
Functional tests		 See 4.3.1d			7, 8	A11			
Input capacitance	CIN	See 4.3.1c			4	A11		10	pF
Output capacitance	COUT	See 4.3.1c	···		4	A11		12	pF
Propagation delay time, Cn to Cn + x,	tpLH1,	V _{CC} = 5.0 V R _L = 500Ω C _L = 50 pF			9, 10, 11	<u> </u>	2.0	16.5	ns
Cn + y, Cn + z	 	See figure 4 <u>5</u> / 	•			02	2.0	10.7 	l I
Propagation delay time, P _O , P ₁ , P ₂ to Cn + x, Cn + y, Cn + z	tpLH2.	 			9,10,11	01 02	1.5	11.5	ns -
Propagation delay time, G _O , G ₁ ,	tpLH3,	<u> </u> 			9, 10, 11	01	1.5	11.5	ns
\overline{G}_2 to $C\bar{n} + \bar{x}$, $C\bar{n} + y$, $C\bar{n} + z$		 				02	1.5	7.4]
Propagation delay \underline{t} ime, \underline{P}_1 , \underline{P}_2 ,	tpLH4,	Г 			9, 10, 11	01	2.0	 16.5 	ns
P ₃ to G		 				02	2.0	 10.7	
See footnotes at end	of table	•							
STANDA!			SIZE A			59	62-886	52	
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$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Test	Symbol	Conditions	Group A	Dev1ce	Li	nits	Unit
Propagation delay tphis, $CC = 50.0\Omega$ $C_L $			-55°C < T _C < +125°C V _{CC} = 5.0 V dc ±10% unless otherwise specified	subgroups	type	Min	Max	<u> </u>
	Propagation delay time, Gn to G	tpLH5,		9, 10, 11	01	2.0	16.5	ns
Propagation delay tpLH6, 9, 10, 11 01 1.5 12.5 ns			See figure 4		 02 	2.0	10.7	
LINE 11 LV 14001 L ' ' '	Propagation delay time, Pn to P	tPLH6,	T - 	9, 10, 11	01	1.5	12.5	ns

- Not more than one output should be shorted at one time, and the duration of the short circuit condition should not exceed 1 second.
- $\underline{2}/$ TTL driven input, V_{IN} = 3.4 V; all other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in total power supply calculations.
- $\underline{\underline{4}}$ / $I_{CC} = I_{CCQ} + (\Delta I_{CC} \times D_H \times N_T) + (I_{CCD}(f_I \times N_I)$

where: DH = Duty cycle for TTL inputs high NT = Number of TTL inputs at DH fI = Input frequency in MHz NI = Number of inputs at fI

5/ The minimum limits are guaranteed, if not tested, to the limits specified in table I.

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De	vice types	01 and	d 02
Ca ou	se tlines	E and F	2
Те	rminal number	Terminal symbol	Terminal symbol
	1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20	で 10033 D + + + + + + + + + + + + + + + + + +	NC 111000 CG P P GO NC G C C NC GP P GO NC G C C NC GP P CC NC P CC NC GP P CC NC GP P CC NC GP P CC NC GP P CC NC P CC NC GP P CC NC P

NC = No connection

FIGURE 1. Terminal connections.

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Definition of functional terms

 Pin names 	Description
c _n	Carry input
₲ ₀ , ₲₂	Carry generate inputs (active low)
\overline{G}_1	Carry generate input (active low)
<u>G</u> 3	Carry generate input (active low)
\overline{P}_0 , \overline{P}_1	Carry propagate inputs (active low)
₱2	Carry propagate input (active low)
P ₃ C _{n + x} - C _{n + z}	Carry propagate input (active low) Carry outputs
G	Carry generate output (active low)
P	Carry propagate output (active low)

FIGURE 1. Terminal connections - Continued.

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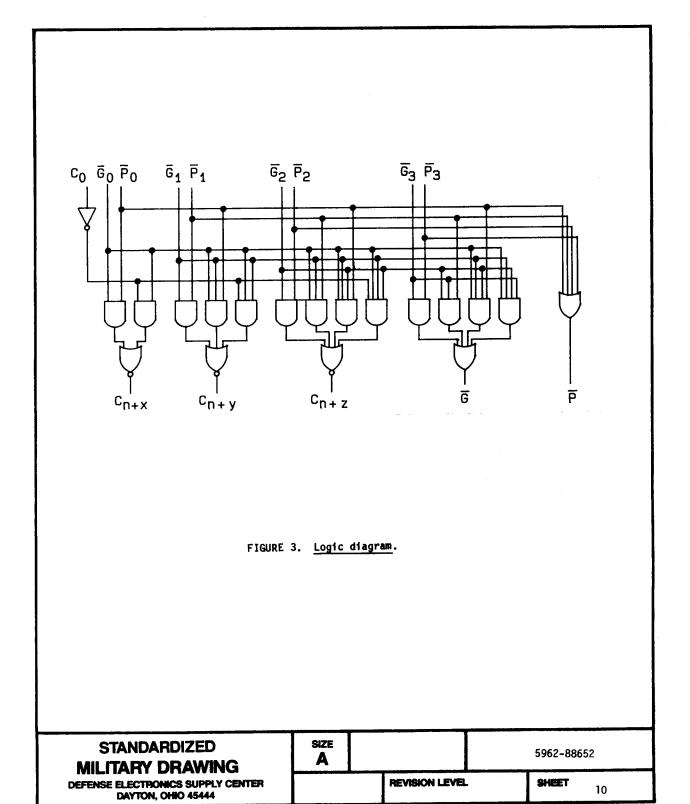
			I	npu	ts					()utputs		-
Cn	G _O	₽0	_{G₁}	₱1	G ₂	P ₂	G	₃ F ₃	C _{n + x}	Cn + y	C _{n + z}	G	P
X L X H	H H L	H X L							 L H H			-	
X X X X H	X H X L	X X X X	H H K X	H X X L L						L L H H			
X X X X X X	X X H X X L	X X H X X X X L	X H H X L X	X H X X X L L	HHHLXX	H X X X L L					L L L H H		
	X X X H X X X		H X X L	X	XHHXLXX	X H X X X L L	H H H H	H				H H H L L	
		H X X X L		X H X X		X X H X L		X X X H L					Н Н Н Н

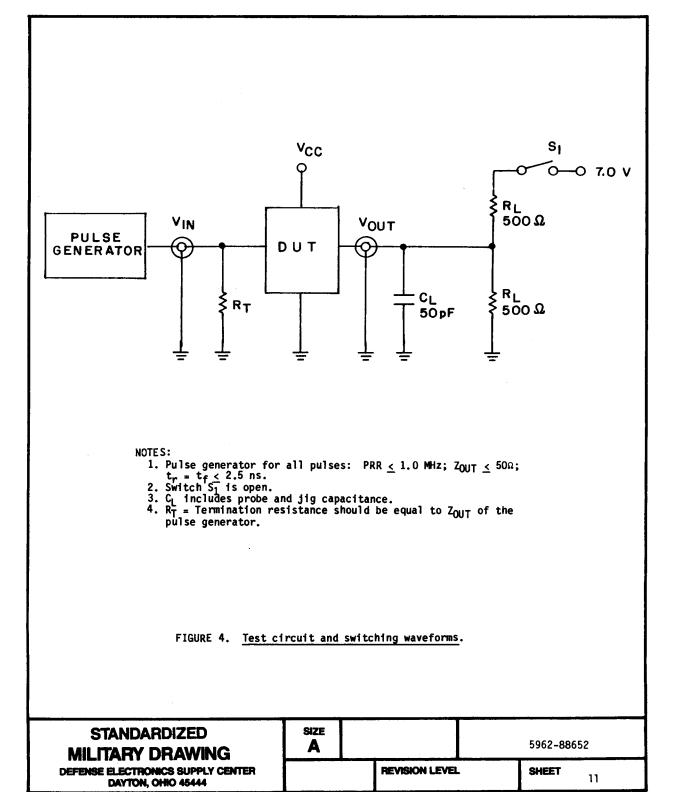
H = High voltage level L = Low voltage level X = Irrelevant

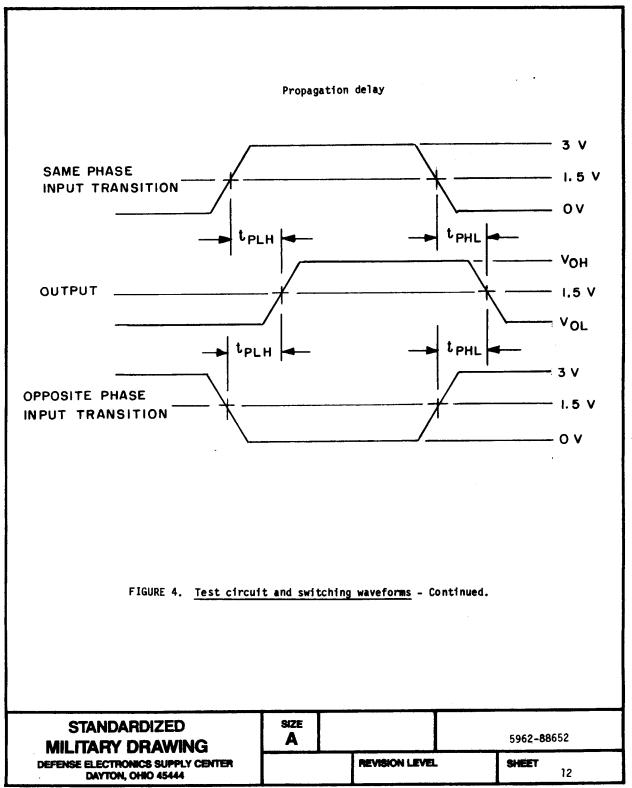
FIGURE 2. Truth table.

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- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 5 and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for the initial test and after process or design changes which may affect capacitance. Test all applicable pins on five devices with zero failures.
 - d. Subgroups 7 and 8 tests shall verify the truth table as specified on figure 2 herein.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
Interim electrical parameters (method 5004)	
Final electrical test parameters (method 5004)	1*,2,3,7,8,9, 10,11
Group A test requirements (method 5005)	1,2,3,4,7,8,9, 10,11
Groups C and D end-point electrical parameters (method 5005)	1,2,3

^{*} PDA applies to subgroup 1.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 Approved source of supply. An approved source of supply is listed herein. Additional sources will be added as they become available. The vendor listed herein has agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number <u>1</u> /
5962-8865201EX	61772	IDT54FCT182DB
5962-8865201FX	61772	IDT54FCT182EB
5962-88652012X	61772	IDT54FCT182LB
5962-8865202EX	61772	IDT54FCT182ADB
5962-8865202FX	61772	IDT54FCT182AEB
5962-88652022X	61772	IDT54FCT182ALB

 $\frac{1}{I}$ Caution. Do not use this number for item acquisition. Items acquired by this number may not satisfy the performance requirements of this drawing.

Vendor CAGE number

Vendor name and address

61772

Integrated Device Technology 3236 Scott Boulevard Santa Clara, CA 95052

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